L Number	Hits	Search Text	DB	Time stamp
1	70	laser and ((adhesive near (layer or region or medium or film))	USPAT;	2002/12/09 08:33
	,	WITH filler) and viscosit\$5	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
15	167	laser and ((adhesive near (layer or region or medium or film)) WITH	USPAT;	2002/12/09 08:11
		viscosit\$5)	US-PGPUB;	
		·	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
8	6	laser and ((adhesive near (layer or region or medium or film))	USPAT;	2002/12/09 07:33
		WITH filler WITH viscosit\$5)	US-PGPUB;	
			EPO; JPO;	
	:		DERWENT;	
			IBM_TDB	
22	53	laser and ((heat\$4 near2 sink) or (cool\$5 near (system or member	USPAT;	2002/12/09 08:41
		OR assembly))) and (adhesive near (layer or region or medium or	US-PGPUB;	
		film)) and ((active or gain) near (medium or film or layer or region))	EPO; JPO;	
		and (densit\$5 or radiat\$5) and thick\$6	DERWENT;	
			IBM_TDB	
29	12	laser and ((heat\$4 near2 sink) or (cool\$5 near (system or member	USPAT;	2002/12/09 08:21
		OR assembly))) and (adhesive near (layer or region or medium or	US-PGPUB;	
		film)) and (((active or gain) near (medium or film or layer or region))	EPO; JPO;	
		with thick\$6)	DERWENT;	
		,	IBM_TDB	
40	1353	laser and ((adhesive near (layer or region or medium or film)) with	USPAT;	2002/12/09 08:39
		(transparent or clear or translucent))	US-PGPUB;	
		"	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
47	433	laser and ((adhesive near (layer or region or medium or film)) near2	USPAT;	2002/12/09 08:41
		(transparent or clear or translucent))	US-PGPUB;	
		<i>"</i>	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
54	1	laser and ((heat\$4 near2 sink) or (cool\$5 near (system or member	USPAT;	2002/12/09 08:44
		OR assembly))) and ((adhesive near (layer or region or medium or	US-PGPUB;	
		film)) near2 (transparent or clear or translucent)) and ((active or	ЕРО; ЈРО;	
		gain) near (medium or film or layer or region))	DERWENT;	
			IBM_TDB	
61	4	laser and ((heat\$4 near2 sink) or (cool\$5 near (system or member	USPAT;	2002/12/09 08:46
	_	OR assembly))) and ((adhesive near (layer or region or medium or	US-PGPUB;	
		film)) WITH (transparent or clear or translucent)) and ((active or	EPO; JPO;	
		gain) near (medium or film or layer or region))	DERWENT;	
			IBM_TDB	
_	1002	(solid near state) and active and amplif\$5 and cool\$4 and thermal\$5	USPAT;	2002/12/02 16:54
		and heat\$4 and laser	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
j			IBM_TDB	
_	391	(solid near state) and active and (laser with amplif\$5) and cool\$4 and	USPAT;	2002/12/02 16:59
ļ		thermal\$5 and heat\$4	US-PGPUB;	
]		T	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	251	((solid near state) and active and (laser with amplif\$5) and cool\$4	USPAT;	2002/12/02 17:01
		and thermal\$5 and heat\$4 ) and \$72/\$	US-PGPUB;	
		··	EPO; JPO;	
			DERWENT;	
			IBM_TDB	l

-	259	(solid near state near laser) and active and (laser with amplif\$5) and cool\$4 and thermal\$5 and heat\$4	USPAT; US-PGPUB;	2002/12/02 17:01
			ЕРО; ЈРО;	
			DERWENT;	
			IBM_TDB	
-	199	((solid near state near laser) and active and (laser with amplif\$5) and	USPAT;	2002/12/03 10:00
		cool\$4 and thermal\$5 and heat\$4 ) and 372/\$	US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM_TDB	
_	154	((solid near state near laser) and active and (laser with amplif\$5) and	USPAT;	2002/12/03 10:03
_	101	cool\$4 and thermal\$5 and heat\$4 ) and liquid and solid and material	US-PGPUB;	2002/ 12/ 00 10:00
		1	ЕРО; ЛРО;	
			DERWENT;	
			IBM_TDB	
-	244	((solid near state) and active and (laser with amplif\$5) and cool\$4	USPAT;	2002/12/03 10:29
		and thermal\$5 and heat\$4 ) and liquid and solid and material	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	160	(((solid near state) and sative and (leser with amplifes) and socie4	IBM_TDB USPAT;	2002/12/03 10:24
-	162	(((solid near state) and active and (laser with amplif\$5) and cool\$4 and thermal\$5 and heat\$4 ) and liquid and solid and material) and	US-PGPUB;	2002/12/03 10:24
		plate	EPO; JPO;	
		Press	DERWENT;	
			IBM_TDB	
-	47	((solid near state) and active and (laser with amplif\$5) and cool\$4	USPAT;	2002/12/03 10:35
		and thermal\$5 same heat\$4 ) and (liquid with solid same material)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		/	IBM_TDB	2002/12/02 10 10
-	55	((solid near state) and active and (laser with amplif\$5) and cool\$4	USPAT; US-PGPUB;	2002/12/03 10:40
		and thermal\$5 and heat\$4 ) and (liquid with solid same material)	EPO; JPO;	
	-		DERWENT;	
			IBM_TDB	
-	113	(solid near state) and semiconductor and active and laser and	USPAT;	2002/12/03 10:44
		amplif\$5 and cool\$4 and thermal\$5 and heat\$4 and (liquid same	US-PGPUB;	
		solid same material)	EPO; JPO;	
			DERWENT;	
		//- 1: 1	IBM_TDB	0000/10/08 17 17
-	84	((solid near state) and semiconductor and active and laser and	USPAT;	2002/12/03 15:17
		amplif\$5 and cool\$4 and thermal\$5 and heat\$4 and (liquid same solid same material)) and plate	EPO; JPO;	
		some same material, and place	DERWENT;	
			IBM_TDB	
-	1	((solid near state with plate) and semiconductor and active and laser	USPAT;	2002/12/03 15:23
		and amplif\$5 and cool\$4 and thermal\$5 and heat\$4 and (liquid same	US-PGPUB;	
		solid same material)) and volum\$5	EPO; JPO;	
	1		DERWENT;	
		///	IBM_TDB	0000/10/08 17 00
_	8	(((solid near state) with plate) and semiconductor and active and	USPAT; US-PGPUB;	2002/12/03 15:26
		laser and amplif\$5 and cool\$4 and thermal\$5 and heat\$4 and (liquid AND solid AND material)) and volum\$5	EPO; JPO;	
		and the state of t	DERWENT;	
			IBM_TDB	
-	20	((solid near state) with plate) and semiconductor and active and laser	USPAT;	2002/12/03 15:33
		and amplif\$5 and cool\$4 and thermal\$5 and heat\$4	US-PGPUB;	
	]		EPO; JPO;	
			DERWENT;	
	L		IBM_TDB	

-	20	(((solid near state) SAME plate) and semiconductor and active and	USPAT;	2002/12/03 15:36
		laser and amplif\$5 and cool\$4 and thermal\$5 and heat\$4 and (liquid	US-PGPUB;	•
		AND solid AND material)) and volum\$5	ЕРО; ЈРО;	
			DERWENT;	
			IBM_TDB	
-	1	(((solid near state) with (body or member or system)) and	USPAT;	2002/12/03 15:45
		semiconductor and (active near (layer or region or medium or film))	US-PGPUB;	
		and (laser with amplif\$5) and (cool\$4 near2 (body or member or	EPO; JPO;	
		system)) and thermal\$5 and heat\$4 and (liquid AND solid AND	DERWENT;	
		material)) and volum\$5	IBM_TDB	
	2	((solid near state) and semiconductor and (active near (layer or	USPAT;	2002/12/03 15:50
_		region or medium or film)) and (laser with amplif\$5) and (cool\$4	US-PGPUB;	2002/12/03 10.00
		near 2 (body or member or system)) and thermal \$5 and heat \$4 and	EPO; JPO;	
			DERWENT;	
		(liquid AND solid AND material)) and volum\$5 and plate		
			IBM_TDB	
-	1	(((solid near state) with (body or member or system)) and	USPAT;	2002/12/03 15:54
		semiconductor and (active near (layer or region or medium or film))	US-PGPUB;	
		and (laser with amplif\$5) and (cool\$4 near2 (body or member or	EPO; JPO;	
	1	system)) and thermal\$5 and heat\$4 and (liquid AND solid AND	DERWENT;	
		material)) and volum\$5 and plate	IBM_TDB	
-	1	((solid near state) and semiconductor and (active near (layer or	USPAT;	2002/12/03 15:58
		region or medium or film)) and (laser with amplif\$5) and cool\$5 and	US-PGPUB;	
		(thermal\$5 near2 (body or member or system)) and heat\$4 and	ЕРО; ЈРО;	
		(liquid AND solid AND material)) and volum\$5 and plate	DERWENT;	
		· ·	IBM_TDB	
_	0	(((solid near state) with (body or member or system)) and	USPAT;	2002/12/03 16:02
		semiconductor and (active near (layer or region or medium or film))	US-PGPUB;	
		and (laser with amplif\$5) and cool\$5 and (thermal\$5 near2 (body or	EPO; JPO;	
		member or system)) and heat\$4 and (liquid AND solid AND	DERWENT;	
		material)) and volum\$5	IBM_TDB	
_	1	((solid near state) and semiconductor and (active near (layer or	USPAT;	2002/12/03 16:06
	•	region or medium or film)) and (laser with amplif\$5) and cool\$5 and	US-PGPUB;	2002, 12, 00 10,00
		(thermal\$5 near2 (body or member or system)) and heat\$4 and	EPO; JPO;	
		(liquid AND solid AND material)) and volum\$5 and plate	DERWENT;	
		(inquite into boild into material)) and volumes and plate	IBM_TDB	
_	95	((solid near state) and semiconductor and (active near (layer or	USPAT;	2002/12/03 16:18
		region or medium or film)) and (laser AND amplif\$5) and (cool\$5)	US-PGPUB:	2002/ 12/ 00 10/10
		and thermal\$5 and heat\$4 and (liquid AND solid AND material))	EPO; JPO;	
		and volum\$5 and plate	DERWENT;	
	•	and volumss and prace		
		//1:1	IBM_TDB	2000/10/00 10 10
<del>-</del>	2	((solid near state) and semiconductor and (active near (layer or	USPAT;	2002/12/03 16:18
		region or medium or film)) and (laser with amplif\$5) and (cool\$5	US-PGPUB;	
		near2 (body or member or system)) and thermal\$5 and heat\$4 and	EPO; JPO;	
		(liquid AND solid AND material)) and volum\$5 and plate	DERWENT;	
			IBM_TDB	
-	8	((solid near state) and semiconductor and (active near (layer or	USPAT;	2002/12/03 16:18
		region or medium or film)) and (laser AND amplif\$5) and (cool\$5	US-PGPUB;	
		near2 (body or member or system)) and thermal\$5 and heat\$4 and	EPO; JPO;	
		(liquid AND solid AND material)) and volum\$5 and plate	DERWENT;	
			IBM_TDB	
-	22	(solid near state) and semiconductor and (active near (layer or region	USPAT;	2002/12/03 16:27
		or medium or film)) and (laser AND amplif\$5) and (cool\$5 near2	US-PGPUB;	
		(body or member or system)) and heat\$4 and plate	EPO; JPO;	
		• "	DERWENT;	
			IBM_TDB	
_	20	(solid near state) and semiconductor and (active near (layer or region	USPAT;	2002/12/03 16:46
		or medium or film)) and (laser AND amplif\$5) and (cool\$5 near2	US-PGPUB;	
		(body or member or system)) and heat\$4 and plate and thermal\$5	EPO; JPO;	
		, , , , , , , , , , , , , , , , , , ,	DERWENT;	
			IBM_TDB	
	L			

				<u></u>
-	15	((solid near state) and semiconductor and (active near (layer or	USPAT;	2002/12/03 16:40
		region or medium or film)) and (laser AND amplif\$5) and (cool\$5	US-PGPUB;	
		near2 (body or member or system)) and heat\$4 and plate and	EPO; JPO;	
		thermal\$5) and (mirror or reflect\$5)	DERWENT;	
			IBM_TDB	
-	40	(solid near state) and (active near (layer or region or medium or	USPAT;	2002/12/04 07:48
		film)) and laser and (cool\$5 near2 (body or member or system)) and	US-PGPUB;	
		heat\$4 and plate and thermal\$5 and (mirror or reflect\$5)	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	8	((solid near state) and (active near (layer or region or medium or	USPAT;	2002/12/03 17:05
		film)) and laser and (cool\$5 near2 (body or member or system)) and	US-PGPUB;	
		heat\$4 and plate and thermal\$5 and (mirror or reflect\$5)) and	EPO; JPO;	
		adhesive	DERWENT;	
			IBM_TDB	
_	7	(solid near state) and (active near (layer or region or medium or	USPAT;	2002/12/04 07:52
		film)) and laser and (cool\$5 near2 (body or member or system)) and	US-PGPUB;	2002/12/01/01/02
		heat\$4 and plate and thermal\$5 and (adhesive near (layer or region	EPO; JPO;	
		or medium or film))	DERWENT:	
		or measure or mini)	IBM_TDB	
_	2	((solid near state) or (solidstate)) and (active near (layer or region or	USPAT;	2002/12/04 08:03
-	2		US-PGPUB;	2002/12/04/08:03
		medium or film)) and laser and (cool\$5 near2 (body or member or		
		system)) and heat\$4 and plate and thermal\$5 and (adhesive near	EPO; JPO;	
		(layer or region or medium or film)) and (mirror or reflect\$5)	DERWENT;	
	_ :	(, 1:1	IBM_TDB	
-	7	((solid near state) or (solidstate)) and (active near (layer or region or	USPAT;	2002/12/04 08:06
		medium or film)) and laser and (cool\$5 near2 (body or member or	US-PGPUB;	
		system)) and heat\$4 and plate and thermal\$5 and (adhesive near	EPO; JPO;	
		(layer or region or medium or film))	DERWENT;	
			IBM_TDB	
-	40	((solid near state) or (solidstate)) and (active near (layer or region or	USPAT;	2002/12/04 08:05
		medium or film)) and laser and (cool\$5 near2 (body or member or	US-PGPUB;	
		system)) and heat\$4 and plate and thermal\$5 and (mirror or	EPO; JPO;	
		reflect\$5)	DERWENT;	
			IBM_TDB	
-	18	(active near (layer or region or medium or film)) and laser and	USPAT;	2002/12/04 08:11
		(cool\$5 near2 (body or member or system)) and heat\$4 and	US-PGPUB,	
	]	thermal\$5 and (adhesive near (layer or region or medium or film))	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	14	((active near (layer or region or medium or film)) and laser and	USPAT;	2002/12/04 08:09
		(cool\$5 near2 (body or member or system)) and heat\$4 and	US-PGPUB;	
		thermal\$5 and (adhesive near (layer or region or medium or film)))	EPO; JPO;	
		and plate	DERWENT;	
			IBM_TDB	
-	7	(active near (layer or region or medium or film)) and laser and	USPAT;	2002/12/04 09:10
		(cool\$5 near (body or member or system)) and heat\$4 and	US-PGPUB;	
		thermal\$5 and (adhesive near (layer or region or medium or film))	ЕРО; ЈРО;	
		and plate	DERWENT:	
		•	IBM_TDB	
_	46	(active near (layer or region or medium or film)) and laser and	USPAT;	2002/12/04 09:13
		heat\$4 near2 sink and thermal\$5 and (adhesive near (layer or region	US-PGPUB;	
		or medium or film))	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	50	(active near (layer or region or medium or film)) and laser and	USPAT;	9009/19/04 1107
-	30	(heat\$4 near2 sink) and (adhesive near (layer or region or medium or		2002/12/04 11:05
			US-PGPUB;	
		film))	EPO; JPO;	
			DERWENT;	
	L		IBM_TDB	

-	500	laser and (heat\$4 near2 sink) and (adhesive near (layer or region or medium or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/04 11:24
-	404	(laser and (heat\$4 near2 sink) and (adhesive near (layer or region or medium or film)) ) and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/12/04 09:58
-	14	(("6344868") or ("6069023") or ("5853622") or ("5644586") or ("5578869") or ("5455462") or ("5329539") or ("5327443") or ("5026748") or ("4990943") or ("4589116") or ("4360965") or ("4126033") or ("4117329")).PN.	IBM_TDB USPAT	2002/12/04 11:24
-	7	laser and (heat\$4 near2 sink) and (adhesive near (layer or region or medium or film)) and ((("6344868") or ("6069023") or ("5853622") or ("5644586") or ("5578869") or ("5455462") or ("5329539") or ("5327443") or ("5026748") or ("4990943") or ("4589116") or ("4360965") or ("4126033") or ("4117329")).PN.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/04 14:44
-	606	laser and ((heat\$4 near2 sink) or (cool\$5 near (system or member))) and (adhesive near (layer or region or medium or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/04 15:28
_	2	(laser and (heat\$4 near2 sink) and (adhesive near (layer or region or medium or film)) and ((("6344868") or ("6069023") or ("5853622") or ("5644586") or ("5578869") or ("5455462") or ("5329539") or ("5327443") or ("5026748") or ("4990943") or ("4589116") or ("4360965") or ("4126033") or ("4117329")).PN.)) and active	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/04 14:39
-	0	laser and (heat\$4 near2 sink) and (adhesive near (layer or region or medium or film)) and ((("6344868") or ("6069023") or ("5853622") or ("5644586") or ("5578869") or ("5455462") or ("5329539") or ("5327443") or ("5026748") or ("4990943") or ("4589116") or ("4360965") or ("4126033") or ("4117329")).PN.) and ((active or	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/04 14:46
-	0	gain) near (medium or film or layer or region)) (laser and (heat\$4 near2 sink) and (adhesive near (layer or region or medium or film)) and ((active or gain) near (medium or film or layer or region))) and ((("6344868") or ("6069023") or ("5853622") or ("5644586") or ("5578869") or ("5455462") or ("5329539") or ("5327443") or ("5026748") or ("4990943") or ("4589116") or ("4360965") or ("4126033") or ("4117329")).PN.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/04 15:13
-	57	laser and (heat\$4 near2 sink) and (adhesive near (layer or region or medium or film)) and ((active or gain) near (medium or film or layer or region))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/04 15:28
-	66	laser and ((heat\$4 near2 sink) or (cool\$5 near (system or member OR assembly))) and (adhesive near (layer or region or medium or film)) and ((active or gain) near (medium or film or layer or region))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/06 11:18
-	8	laser and (((heat\$4 near2 sink) or (cool\$5 near (system or member OR assembly))) same (adhesive near (layer or region or medium or film))) and ((active or gain) near (medium or film or layer or region))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/04 16:04
-	56	laser and ((heat\$4 near2 sink) or (cool\$5 near (system or member OR assembly))) and (adhesive near (layer or region or medium or film)) and ((active or gain) near (medium or film or layer or region)) and (densit\$5 or radiat\$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/09 08:12

_	33	(laser and ((heat\$4 near2 sink) or (cool\$5 near (system or member	USPAT;	2002/12/06 13:20
		OR assembly))) and (adhesive near (layer or region or medium or	US-PGPUB;	
		film)) and ((active or gain) near (medium or film or layer or region))	EPO; JPO;	
		and (densit\$5 or radiat\$5)) and solid and liquid\$5	DERWENT;	
	ļ		IBM_TDB	
-	74	laser and ((adhesive near (layer or region or medium or film)) same	USPAT;	2002/12/09 08:12
		liquid same solid)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
	28	laser and ((adhesive near (layer or region or medium or film))	USPAT;	2002/12/06 14:07
		WITH liquid with solid)	US-PGPUB;	
		·	EPO; JPO;	
		·	DERWENT;	
			IBM_TDB	
	200	laser and ((adhesive near (layer or region or medium or film))	USPAT;	2002/12/06 14:09
		WITH filler)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
	200	laser and ((adhesive near (layer or region or medium or film))	USPAT;	2002/12/09 07:26
		WITH filler)	US-PGPUB;	
	ĺ		EPO; JPO;	
			DERWENT;	
			IBM_TDB	